

TECHNICAL DATA DATASHEET 4753, REV. B

SILICON SCHOTTKY RECTIFIER Ultra Low Reverse Leakage 175°C Operating Temperature

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--------------------|---|-------------|-------|
| Peak Inverse Voltage | V_{RWM} | - | 45 | V |
| Max. Average Forward Current | I _{F(AV)} | Maximum DC Output Current (@ T _C =100 ^o C) (Single, Doubler) | 7.5 | A |
| Max. Average Forward Current | I _{F(AV)} | Maximum DC Output Current (@ T _C =100 ^o C) (Common Cathode, Common Anode) | 15 | A |
| Max. Peak One Cycle Non- Repetitive Surge Current | I _{FSM} | 8.3 ms, half Sine wave | 75 | Α |
| Maximun Thermal Resistence (Per leg) | $R_{	heta JC}$ | - | 5.37 | °C/W |
| Max. Junction Temperature | T_J | - | -65 to +175 | °C |
| Max. Storage Temperature | T_{stg} | - | -65 to +175 | °C |

Electrical Characteristics Per Leg:

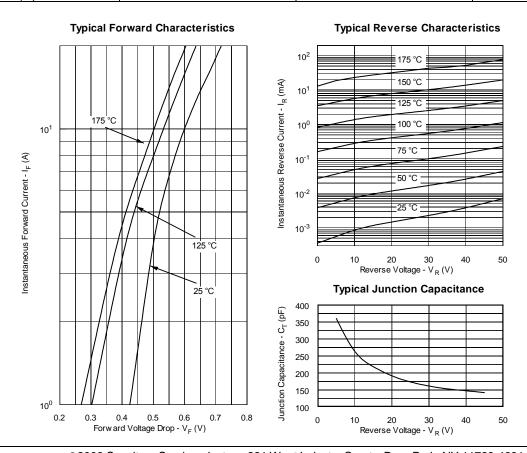
| Characteristics | Symbol | Condition | Max. | Units |
|---------------------------|-----------------|---|------|-------|
| Max. Forward Voltage Drop | V_{F1} | @ 7.5 A, Pulse, T _J = 25 °C | 0.73 | V |
| | V_{F2} | @ 7.5 A, Pulse, T _J = 125 °C | 0.66 | V |
| Max. Reverse Current | I _{R1} | @V _R = 45 V, Pulse, | 0.2 | mA |
| | | T _J = 25 °C | | |
| | I _{R2} | @V _R = 45 V, Pulse, | 7.5 | mA |
| | | T _J = 125 °C | | |
| Max. Junction Capacitance | C _T | $@V_R = 5V, T_C = 25 ^{\circ}C$ | 400 | pF |
| | | $f_{SIG} = 1MHz,$ | | |
| | | $V_{SIG} = 50 \text{mV (p-p)}$ | | |

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Mechanical Dimensions: In Inches / mm .200 (5.08 .<u>150</u> (3.81 Dia. .420 (10.67 .190 4.82) .410 10.41) .045 (1.14 .035 0.89) .665 (16.89 .537 (13.64 .645 16.38) .430 (10.92 .410 10.41) 1.132 (28.75 1.032 26.21) .035 (0.89 .025 0.63) .100(2.54) BSC 2 Places - .120(3.05) BSC

TO-257

| DEVICE TYPE | PIN 1 | PIN 2 | PIN 3 |
|--------------------|-----------|-----------------|-----------|
| SINGLE RECTIFIER | CATHODE | ANODE | ANODE |
| COMMON CATHODE (P) | ANODE 1 | COMMON CATHODE | ANODE 2 |
| COMMON ANODE (N) | CATHODE 1 | COMMON ANODE | CATHODE 2 |
| DOUBLER (D) | ANODE | CATHODE / ANODE | CATHODE |



SENSITRON

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Note: Vf characteristics are for unpackaged die only.

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